

# Publikačný seminár

**J. Osvald:**

„Interface traps contribution to capacitance of Al<sub>2</sub>O<sub>3</sub>/(GaN)AlGaN/GaN heterostructures at low frequencies“

*Physica E*

**M. Ľapajna:**

„Investigation of ‘surface donors’ in Al<sub>2</sub>O<sub>3</sub>/AlGaN/GaN metal-oxide-semiconductor heterostructures: Correlation of electrical, structural, and chemical properties“

*Applied Surface Science*

**B. Brunner:**

„Properties of MgB<sub>2</sub> wires doped with BaZrO<sub>3</sub> nanopowder made by modified internal magnesium diffusion process“

*Superconductor Science & Technology*

**Čas: 18. august 2017 o 10:00 hod.**

**Miesto: malá zasadačka EIÚ SAV, miestnosť 101**